

◆ Features:

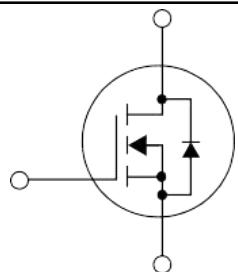
- ◊ Fast switching speed
开关速度快
- ◊ High input impedance and low level drive
高输入阻抗和低电平驱动
- ◊ Avalanche energy tested
雪崩能量测试
- ◊ Improved dv/dt capability, high ruggedness
提高 dv/dt 能力，高耐用性

TO-220F

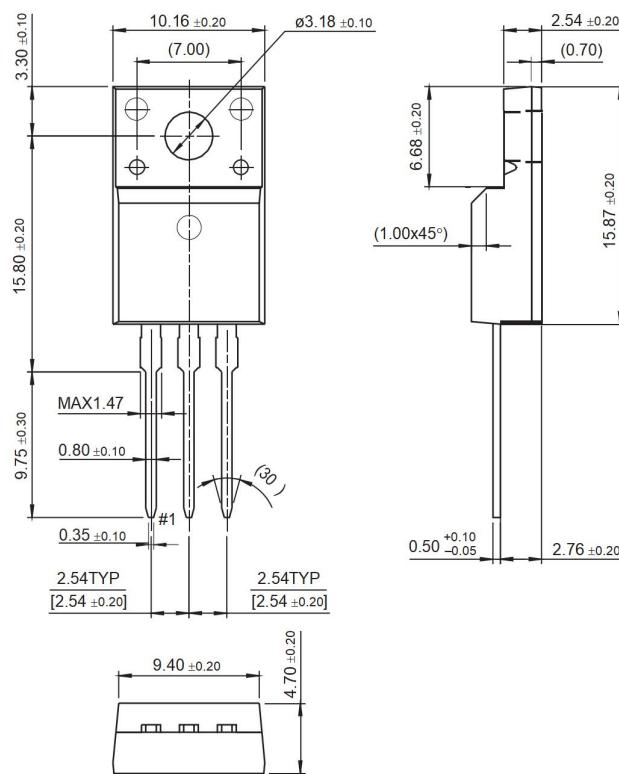


◆ Applications

- ◊ High efficiency switch mode power supplies
高效率开关电源
- ◊ Power factor correction
功率因数校正
- ◊ Electronic lamp ballast
电子整流器



TO-220F



◆ Absolute Maximum Ratings (Tc=25°C)

Symbol	Parameters	Ratings	Unit
V _{DSS}	Drain-Source Voltage 漏源电压	500	V
V _{GS}	Gate-Source Voltage-Continuous 栅源电压	±30	V
I _D	Drain Current-Continuous (Note 2) 漏极持续电流	9	A
I _{DM}	Drain Current-Single Plused (Note 1) 漏极单次脉冲电流	32	A
P _D	Power Dissipation (Note 2) 功率损耗	42	W
T _j	Max.Operating junction temperature 最大结温	150	°C

◆ Electrical characteristics (Tc=25°C unless otherwise noted)

Symbol	Parameters	Min	Typ	Max	Units	Conditions
Static Characteristics						
B _{VDSS}	Drain-Source Breakdown VoltageCurrent (Note 1) 漏极击穿电压	500	--	--	V	I _D =250μA, V _{GS} =0V, T _j =25°C
V _{GS(th)}	Gate Threshold Voltage 栅极开启电压	2.0	--	4.0	V	V _{DS} =V _{GS} , I _D =250μA
R _{DS(on)}	Drain-Source On-Resistance 漏源导通电阻	--	0.7	0.85	Ω	V _{GS} =10V, I _D =4.5A
I _{GSS}	Gate-Body Leakage Current 栅极漏电流	--	--	±100	nA	V _{GS} =±30V, V _{DS} =0

I_{DSS}	Zero Gate Voltage Drain Current 零栅极电压漏极电流	--	--	1	μA	$V_{DS}=500V, V_{GS}=0$
Switching Characteristics						
$T_{d(on)}$	Turn-On Delay Time 开启延迟时间	--	13.6	37.2	ns	$V_{DS}=250V, I_D=9A,$ $R_G=25\Omega$ (Note 2)
T_r	Rise Time 上升时间	--	9.1	28.2	ns	
$T_{d(off)}$	Turn-Off Delay Time 关闭延迟时间	--	42	94	ns	
T_f	Fall Time 下降时间	--	10	30	ns	
Q_g	Total Gate Charge 栅极总电荷	--	43	56	nC	
Q_{gs}	Gate-Source Charge 栅源极电荷	--	7.5	--	nC	
Q_{gd}	Gate-Drain Charge 栅漏极电荷	--	18.5	--	nC	
Dynamic Characteristics						
C_{iss}	Input Capacitance 输入电容	--	1130	1505	pF	$V_{DS}=25V, V_{GS}=0,$ $f=1MHz$
C_{oss}	Output Capacitance 输出电容	--	45	60	pF	
C_{rss}	Reverse Transfer Capacitance 反向传输电容	--	20	35	pF	
I_s	Continuous Drain-Source Diode Forward Current (Note 2) 二极管导通正向持续电流	--	--	9	A	
V_{SD}	Diode Forward On-Voltage 二极管正向导通电压	--	--	1.4	V	$I_s=9A, V_{GS}=0$
$R_{th(j-e)}$	Thermal Resistance, Junction to Case 结到外壳的热阻	--	--	2.62	$^{\circ}C/W$	

Note 1: Repetitive Rating : Pulse width limited by maximum junction temperature

Note 2: Pulse test: PW <= 300us , duty cycle <= 2%.